

## Robustness of Decoherence-Free States for Charge Qubits under Local Non-uniformity

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We analyze the robustness of decoherence-free (DF) subspace and subsystem in charge qubits, when difference from the collective decoherence measurement condition is large (5%) in the long time period, which is applicable for solid-state qubits using as a quantum memory. We solve master equations of up to four charge qubits and a detector as a quantum point contact (QPC). We show that robustness of DF states is strongly affected by local non-uniformities. We also discuss the possible two-qubit logical states by exactly solving the master equations.

Although decoherence is the largest obstacle for quantum information processing, a lot of powerful active methods for correcting effects of decoherence have been discovered<sup>1</sup>. As to the passive anti-decoherence protection, decoherence-free (DF) subspace<sup>2,3</sup> and subsystem<sup>4</sup> are shown to be very useful for collective decoherence environment, in which all qubits suffer the same disturbance from the environment. Singlet state is the only DF state for two qubits and there are two independent DF subspace bases for four qubits, e.g.

$$\begin{aligned} |j_1^{[4]} i_{(1234)}\rangle &= 2^{-1} (|j_1 i_1 j_2 i_2\rangle_{(12)} - |j_1 i_1 j_3 i_3\rangle_{(34)}); \\ |j_2^{[4]} i_{(1234)}\rangle &= 1 = (2^{-1/2}) (|j_1 i_1 j_2 i_3\rangle - |j_1 i_1 j_2 i_4\rangle - |j_1 i_1 j_3 i_4\rangle - |j_1 i_1 j_4 i_4\rangle \\ &\quad - |j_2 i_1 j_3 i_4\rangle + 2 |j_2 i_1 j_4 i_4\rangle)_{(1234)} \end{aligned} \quad (1)$$

where  $|j_1 i_1 j_2 i_3 j_3 i_4\rangle$  and so on. The DF subsystem starts from three qubits. Experiments have succeeded until four qubits in photon system<sup>5,6</sup> and three qubits in nuclear magnetic resonance (NMR)<sup>7</sup>. Bacon et al.<sup>3</sup> also showed that, even if there is a symmetry breaking perturbation from the collective environment, which is parameterized by a coupling strength  $J$ , the DF subspace is robust in the order of  $O(J)$  when  $J \ll 1$ .

However, in the case of solid-state qubits, even a single qubit is hard to fabricate and the redundancy regarding the number of qubits would be a critical issue in constructing a large qubit system. First of all, we could not prepare plenty of qubits with mathematically exact size. The sizes of Cooper-pair box of Ref.<sup>8</sup> and GaAs quantum dot (QD)<sup>9</sup> where coherent oscillation can be observed are less than hundreds of nm. The requirement of a few % fluctuation between qubits would result in controllability of a few nm in fabrication. This would be unrealistic until future when fabrication process is greatly advanced. The fluctuation of sizes would lead to that of interaction amplitude between qubits and a measurement apparatus, and that of the applied gate bias, in addition to the effect of randomly distributed background traps<sup>10,11</sup>. Note that even a roughness of the order of 1 Å at interfaces affects current characteristics in advanced LSI technologies as shown in Ref.<sup>12</sup> Thus, the non-uniformity of solid-state qubits to collective decoherence environment is much larger and rather local compared with that of optical or NMR qubits, and it will be necessary to consider the effects of second order  $O(J^2)$  or higher symmetry-breaking perturbation.

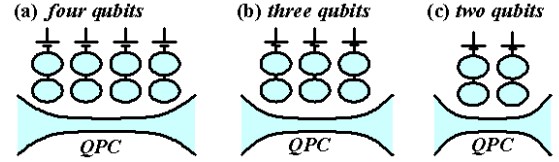


FIG. 1: Qubits that use double dot charged states are capacitively coupled to a QPC detector.

In this paper, we theoretically describe the effect of large non-uniformity (5%) of charge qubit parameters on DF states based on time-dependent density matrix (DM) equations considering the measurement process by detector current. Detection of qubit states induces a backaction on the qubit state resulting in a corrupting of qubit states. Thus, the measurement is an important interaction with the environment for qubits. The charge qubit is a two-level system<sup>13</sup> controlled by gate electrodes<sup>10,14</sup>, and constituted from coupled QDs where one excess electron is inserted, assuming there is one energy level in each QD. The detector discussed here is a quantum point contact (QPC) in the tunneling region depicted in Fig.1. The position of the excess charge affects the QPC current electrically, resulting in detection of charged state. Experiments<sup>15,16</sup> have successfully proved the high sensitivity of QPC detector current  $I = G_0 T v_d$  ( $G_0 = 2e^2/h \approx 77$  S,  $T$  is a transmission coefficient  $v_d$  is a bias between electrodes) in the tunneling region ( $T < 1$ ). The QPC current induces shot noise as the basic and unavoidable noise<sup>16</sup>, and the cause of decoherence treated here. The purpose of this study is to investigate the robustness of any-qubit DF states for local large non-uniformity and show the possibility of using non-DF states with two-qubit singlet states during the QPC measurement. Two-qubit DM is analytically solved and perfectly analyzed.

The Hamiltonian for the combined qubits and the QPC is written as  $H = H_{qb} + H_{qpc} + H_{int}$ .  $H_{qb}$  describes the interacting  $N$  qubits (Fig.):  $H_{qb} = \sum_{i=1}^N (\epsilon_i \sigma_i^x + \epsilon_i \sigma_i^z) + \sum_{i=1}^{N-1} J_{i,i+1} \sigma_i^z \sigma_{i+1}^z$ ; where  $\epsilon_i$  and  $J_{i,i+1}$  are the inter-QD tunnel coupling and energy difference (gate bias) within each qubit. Here the spin operators are expressed by annihilation operators of an electron in the upper and lower QDs of each qubit.  $J_{i,i+1}$  is a coupling constant

between two nearest qubits, originating from capacitive couplings in the QD system<sup>14</sup>.  $j_i$  and  $j_{\#i}$  refer to the two single-qubit states in which the excess charge is localized in the upper and lower dot, respectively.  $H_{QPC} = \sum_{i_L, i_R} E_i C_{i_L, S}^\dagger C_{i_L, S} + \sum_{i_L, i_R} V_S (C_{i_L, S}^\dagger C_{i_R, S} + C_{i_R, S}^\dagger C_{i_L, S})$  describes the QPC. Here  $C_{i_L, S} (C_{i_R, S})$  is the annihilation operator of an electron in the  $i_L$  ( $i_R$ ) level ( $i_L (i_R) = 1; \dots; n$ ) of the left (right) electrode.  $H_{int}$  is the (capacitive) interaction between the qubits and the QPC, that induces dephasing between different eigenstates of  $i_z$ <sup>2</sup>. Most importantly, it contains the fact that localized charge near the QPC increases the energy of the system electrostatically, thus affecting the tunnel coupling between the left and right electrodes:

$$H_{int} = \sum_{i_L, i_R; s} V_{is} i_z (C_{i_L, S}^\dagger C_{i_R, S} + C_{i_R, S}^\dagger C_{i_L, S}): \quad (2)$$

Note that the case where  $V_i$  is independent of the qubit corresponds to collective environment, thus the DF states are realized. Hereafter we neglect the spin dependence of  $V$  and  $V_i$ . We assume that the tunneling rate through the  $N$  qubits,  $\Gamma$ , is composed of direct series of each  $N$  tunneling rate near  $i$ -th qubit,  $\Gamma_i$ , such as  $\Gamma = \prod_{i=1}^N \Gamma_i$ , where  $\Gamma_i$  is defined as  $\Gamma_i = \frac{1}{2} \sum_{i_L, i_R} \langle \rho_{i_L, i_R} \rangle (V_{i_L, S} - V_{i_R, S})^2$  ( $\rho_{i_L, i_R}$  and  $\rho_{i_R, i_L}$  are the density of states of the electrodes at the Fermi surface) depending on the qubit state  $i_z = \pm 1$ . The strength of measurement is parameterized by  $\Gamma_i$  as  $\Gamma_i = \Gamma_{i0} \Gamma_i$ . We call  $j_{\#i}$ ,  $j_{\#i}$ ,  $j_{\#i}$ , and  $j_{\#i}$  as  $\mathcal{A}_i$ ,  $\mathcal{B}_i$ ,  $\mathcal{C}_i$ , and  $\mathcal{D}_i$  respectively, and four-qubit states are written by  $\mathcal{A}_i \mathcal{A}_i \mathcal{B}_i \mathcal{C}_i \mathcal{D}_i$ . For uniform two qubits,  $\mathcal{A} = \mathcal{B} = \mathcal{C} = \mathcal{D} = 0$  ( $\Gamma = 2$ ) and  $\mathcal{D} = 0$  ( $\Gamma = 2$ ) with  $\mathcal{A} = 0$ . The DM equations of  $N$  qubits and detector at zero temperature are derived similar to Ref.<sup>17</sup> as

$$\frac{d}{dt} \rho_{z_1 z_2} = i [\mathcal{J}_{z_2}, \rho_{z_1 z_2}] - \sum_{j=1}^N \Gamma_j (g_j(z_1) \rho_{z_1 z_2} - \rho_{z_1 z_2} g_j(z_2)) \quad (3)$$

where  $z_1, z_2 = \mathcal{A}, \mathcal{B}, \mathcal{C}, \mathcal{D}$  for four qubits (256 equations) and  $z_1, z_2 = \mathcal{A}, \mathcal{B}, \mathcal{C}, \mathcal{D}$  for two qubits (16 equations).  $\mathcal{J}_{\mathcal{A}\mathcal{A}} = \mathcal{J}_{\mathcal{A}\mathcal{B}} + \mathcal{J}_{\mathcal{A}\mathcal{C}} + \mathcal{J}_{\mathcal{A}\mathcal{D}}$ ,  $\mathcal{J}_{\mathcal{B}\mathcal{B}} = \mathcal{J}_{\mathcal{B}\mathcal{A}} + \mathcal{J}_{\mathcal{B}\mathcal{C}} + \mathcal{J}_{\mathcal{B}\mathcal{D}}$ ,  $\mathcal{J}_{\mathcal{C}\mathcal{C}} = \mathcal{J}_{\mathcal{C}\mathcal{A}} + \mathcal{J}_{\mathcal{C}\mathcal{B}} + \mathcal{J}_{\mathcal{C}\mathcal{D}}$ ,  $\mathcal{J}_{\mathcal{D}\mathcal{D}} = \mathcal{J}_{\mathcal{D}\mathcal{A}} + \mathcal{J}_{\mathcal{D}\mathcal{B}} + \mathcal{J}_{\mathcal{D}\mathcal{C}}$ .  $g_1(z_1)$  and  $g_2(z_2)$  are introduced for the sake of notational convenience and determined by the relative positions between qubit states. For two qubits,  $g_1(\mathcal{A}) = \mathcal{B}$ ,  $g_2(\mathcal{A}) = \mathcal{C}$ ,  $g_1(\mathcal{B}) = \mathcal{A}$ ,  $g_2(\mathcal{B}) = \mathcal{D}$ ,  $g_1(\mathcal{C}) = \mathcal{D}$ ,  $g_2(\mathcal{C}) = \mathcal{A}$ ,  $g_1(\mathcal{D}) = \mathcal{B}$ ,  $g_2(\mathcal{D}) = \mathcal{C}$ . Because the detector current is  $I = e \sum_{z=\mathcal{A}; \dots; \mathcal{D}} z \rho_{zz}$ , we have  $T = T_0 = 0$  ( $\Gamma = 0$ )<sup>18</sup>. In the two-qubit case, we use entangled Bell basis:  $\mathcal{A}_i \mathcal{B}_i + \mathcal{C}_i \mathcal{D}_i = \sqrt{2}$ ,  $\mathcal{A}_i \mathcal{B}_i - \mathcal{C}_i \mathcal{D}_i = \sqrt{2}$ ,  $\mathcal{A}_i \mathcal{C}_i + \mathcal{B}_i \mathcal{D}_i = \sqrt{2}$ ,  $\mathcal{A}_i \mathcal{C}_i - \mathcal{B}_i \mathcal{D}_i = \sqrt{2}$ .

Decoherence rates (From Eq. (3), the dephasing is expected to be relevant to the dephasing rate  $\Gamma_d(z_1, z_2) = \sum_{j=1}^N \Gamma_j [g_j(z_1) - g_j(z_2)]^2$ . To see the decoherence effect explicitly, we study time-dependent density,  $F(t)$

$\text{Tr}[\rho(0) \rho(t)]$  on the rotating coordinate as  $\rho(t) = e^{i \sum_{i=1}^N i_z \tau} \rho e^{-i \sum_{i=1}^N i_z \tau}$  ( $\rho = \frac{1}{2} \sum_{i=1}^N \frac{1}{i!} \tau^i \rho^{(i)}$ ) to eliminate the bonding-antibonding coherent oscillations of free qubits (trace is carried out over qubit states).  $F(t)$  can be expanded in time as  $F(t) = 1 - \sum_{n=1}^{\infty} \frac{(1-n)!}{n!} (t \Gamma)^n$  where  $1 = (1-n)! = \text{Tr}[\rho(0) \rho^{(n)}] = \text{Tr}[\rho^{(n)}]$  (decoherence rates). Using Eq.(3) for two qubits,  $1 = \frac{(1)!}{1!} = \frac{(1)!}{1!} = (1-2) \Gamma_d(\mathcal{B}; \mathcal{C}) = (0-8) \Gamma_d(\mathcal{B}; \mathcal{C})$  when  $\mathcal{B}$  and  $\mathcal{C}$  are not symmetric such as the left qubit has a local fluctuation  $\Gamma_d(\mathcal{B}) = 1$ . Moreover,  $(1 = \frac{(1)!}{1!})^2 = (\frac{1}{2} + \frac{1}{2})^2 + (\frac{1}{2} - \frac{1}{2})^2 + \frac{1}{4} \Gamma_d(\mathcal{B}; \mathcal{C}) = 4$  and  $(1 = \frac{(1)!}{1!})^2 = (\frac{1}{2} - \frac{1}{2})^2 + (\frac{1}{2} + \frac{1}{2})^2 + \frac{1}{4} \Gamma_d(\mathcal{B}; \mathcal{C}) = 4$ . Thus, the symmetry-breaking terms start from  $O(\Gamma^2)$ . We have similar expressions for three-qubit DF subsystem and four-qubit DF subspace. For  $j_1^{[3]} i_1$  ( $j_1^{[3]} i_1$ ),  $1 = \frac{(1)!}{1!} = (1-2) \Gamma_d(010; 100)$  and for  $j_1^{[4]} i_{(1234)}$ ,

$$\frac{1}{1!} = \frac{1}{8} \sum_{z_1, z_2 = \mathcal{A}, \mathcal{B}, \mathcal{C}, \mathcal{D}} \Gamma_d(z_1; z_2); \quad (4)$$

both of which also start from  $O(\Gamma^2)$  (decoherence rate of  $j_2^{[4]} i_{(1234)}$  has a similar but more complicated form). The robustness of  $N=3$  qubits changes depends on which qubit includes local fluctuation. For example, if the leftmost qubit of  $j_1^{[3]} i_1$  fluctuates,  $1 = \frac{(1)!}{1!} = 0$  when the rightmost qubit fluctuates. In the latter case, there is a symmetry between the leftmost and middle qubit and we can say that if some symmetry remains, DF states are robust. To see the dependence of spatial arrangement of qubits, we also consider  $j_3^{[4]} i_{(1234)}$  and  $j_1^{[4]} i_{(1423)}$  (hereafter we omit the subscript).  $j_3^{[4]} i_1$  is expected to be more susceptible than  $j_1^{[4]} i_1$ , because the former is not a product of two singlet states as  $j_1^{[4]} i_1$  and less symmetric exchanges of qubit states are possible when qubit parameters fluctuate. Thus, the DF states are strongly affected by the distribution of local non-uniformities.

Numerical calculations support these analyses. Here we add fluctuations locally to  $i_1$ ,  $i_2$  and  $i_3$  respectively to various DF states of  $N \leq 4$  qubits. In case (i), only 3rd qubit fluctuates as  $j_3^{[3]} i_1$  ( $\Gamma = 1$ ),  $j_3^{[3]} i_1$  ( $\Gamma = 1$ ) and  $j_3^{[3]} i_1$  ( $\Gamma = 1$ ). In case (ii), the 2nd and 3rd qubits fluctuate. In case (iii) only 4th qubit fluctuates. Fig. 2 (a) shows a time-dependent  $F(t)$  in a strong measurement case of  $\Gamma = 0.6$  of 1% fluctuations ( $\Gamma = 0.01$ ) and Fig. 2 (b) shows that of a weak measurement case of  $\Gamma = 0.2$  of 5% fluctuations ( $\Gamma = 0.05$ ), both in degeneracy point  $\Gamma = 0$  (relaxation decoherence region<sup>10,11</sup>). Although Fig. 2 (a) indicates that the four-qubit DF states are fairly robust, Fig. 2 (b) shows that the large fluctuation (5%) greatly degrades  $j_3^{[4]} i_1$  in case (iii). If we take  $\Gamma_0 = 100 \text{ MHz}$ , its lifetime ( $F(t) > 0.75$ ) is about  $50 \times 10^{-1} = 500 \text{ ns}$ , which is much shorter than lowest order estimation of  $\Gamma_0^{-1} = 40 \text{ s}$ . This shows that higher symmetry-breaking perturbation terms cannot be

neglected and there is a case where a product state is more preferable than four-qubit DF states.  $F(t)$  for  $j_2^{[4]}i$  is in the same order of  $j_1^{[4]}i$ , which means that DF states composed of many entangled states seem fairly robust at the degeneracy point. The three-qubit DF states are fairly robust for larger  $\eta$ , and show susceptibilities to measurement strength as the singlet state and other Bell states (Fig. 2(a)). In the case of finite bias (pure dephasing region), the effect of which appears from  $1 = \langle J_{ij} \rangle$ ,  $F(t)$  of  $j_2^{[4]}i$  and  $j_3^{[4]}i$  seem more susceptible than the singlet state and the singlet type  $j_1^{[4]}i$  (Fig. 3). The other Bell states and three-qubit DF states are less susceptible than  $j_2^{[4]}i$  and  $j_3^{[4]}i$ , which would again be due to the higher order symmetry-breaking terms. To summarize these results, DF states of many qubit ( $N = 4$ ) are robust for most cases but there is a case where even product states might be better under large symmetry-breaking fluctuations ( $\eta > 5\%$ ) in the long term.

Analytical solution for two-qubit case: The probability that the unexpected non-uniformities induce symmetry-breaking effects becomes higher as the number of qubits increases as shown above. Because preparing many solid-state qubits is not easy, the redundancy of coding qubits is a trade-off against the fabrication difficulty. Thus, using the singlet state and one of the non-DF states,  $|f_{aa}; b_b; c_c\rangle$  in two-qubit space would sometimes be a realistic solution to construct two logical states  $|j_{Li}\rangle$  and  $|j_{Li}\rangle$ . Here we investigate which of  $|f_{aa}; b_b; c_c\rangle$  is appropriate for the second basis in two-qubit space. When we move to four Bell bases under the conditions that the two qubits are identical with no interaction between them ( $J_{ij} = 0$ ) and no bias  $\epsilon_i = 0$  (collective environment), Eqs.(3) are divided into the following five groups:

$$\dot{a}_{dd} = 0 \quad (5)$$

$$\dot{a}_{bd} = -B_{bd} a_{bd} \quad (6)$$

$$\dot{a}_{ad} = 2i \omega_{cd} a_{ad} - B_{ad} a_{ad} \quad (7)$$

$$\dot{a}_{ab} = 2i \omega_{cb} a_{ab} + \frac{1}{2} D_{ab} (a_{ba} - a_{ab}) \quad (8)$$

$$\begin{aligned} \dot{a}_{bc} &= 2i \omega_{ba} a_{bc} - \frac{1}{2} D_{bc} (a_{ba} - a_{bc}) \\ \dot{a}_{aa} &= 2i (\omega_{ac} - \omega_{ca}) a_{aa} + \frac{1}{2} D_{aa} (a_{aa} - a_{bb}) \\ \dot{a}_{bb} &= \frac{1}{2} D_{bb} (a_{aa} - a_{bb}) \\ \dot{a}_{cc} &= 2i (\omega_{ac} - \omega_{ca}) a_{cc} \\ \dot{a}_{ac} &= 2i (\omega_{aa} - \omega_{cc}) a_{ac} \end{aligned} \quad (9)$$

where  $D_{ij} = \omega_{ij} - \omega_{ji}$  and  $B_{ij} = \omega_{ij} + \omega_{ji}$ . These equations can be solved analytically. First, singlet state  $a_{dd}$  is time-independent (DF state) and  $a_{bd}(t) = \frac{a_{bd}(0)e^{-B_{bd}t}}{e^{-(B_{bd})^2 - 16\omega_{bd}^2}t}$ , and  $a_{ad}(t)$  and  $a_{cd}(t)$  behave like  $e^{-(B_{ad} + D_{ad})^2 - 16\omega_{ad}^2}t}$ , thus decay rates of  $a_{ad}(t)$ ,  $a_{cd}(t)$ ,  $a_{ab}(t)$  and  $a_{bc}(t)$  depend on whether  $4 > B_{ij}^2$ ,  $B_{ij}^2 + D_{ij}^2$  or  $4 < B_{ij}^2$ ,  $B_{ij}^2 + D_{ij}^2$ , respectively. From Eq.(9),  $a_{aa}(t) + a_{bb}(t) + a_{cc}(t)$  is conserved and  $a_{ac}(t) + a_{ca}(t) = (a_{ac}(0) + a_{ca}(0))e^{-B_{ac}t}$ . Thus,  $a_{aa}(t)$ ,  $a_{bb}(t)$ ,  $a_{cc}(t)$  and

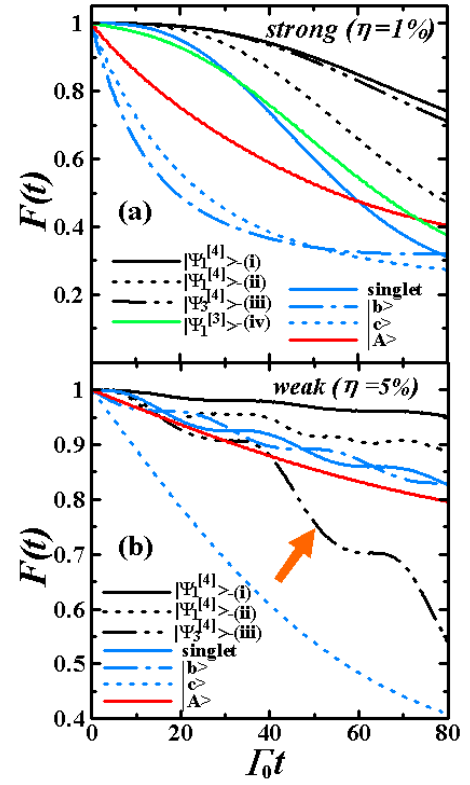


FIG. 2: Time-dependent fidelity of four-qubit DF states ( $j_1^{[4]}i$  and  $j_3^{[4]}i$ ) three-qubit DF state of  $j_1^{[3]}i$ , and two-qubit states (singlet,  $|j_{Li}\rangle$ ,  $|j_{Li}\rangle$ , and product state  $|j_{Li}\rangle$ ) under various fluctuations: (i)  $\epsilon_3 = (1, 0)$ ,  $\epsilon_3 = 0$  and  $\epsilon_3^{(1)} = (1, 0)$ . (ii)  $\epsilon_2 = \epsilon_3 = (1, 0)$ ,  $\epsilon_2 = \epsilon_3 = 0$  and  $\epsilon_2^{(1)} = \epsilon_3^{(1)} = (1, 0)$ . (iii)  $\epsilon_4 = (1, 0)$ ,  $\epsilon_4 = 0$  and  $\epsilon_4^{(1)} = (1, 0)$ . (iv)  $\epsilon_2 = (1, 0)$ ,  $\epsilon_2 = 0$  and  $\epsilon_2^{(1)} = (1, 0)$ . (iv) is also applied to the two qubits. (a)  $\eta = 0.01$  and  $\eta = 0.6$  (strong measurement), (b)  $\eta = 0.05$  and  $\eta = 0.2$  (weak measurement).  $\epsilon_i = 2, J_{ij} = 0, \epsilon_i = 0$ .

$a_{ac}(t)$  can be analytically obtained by solving three-order polynomial equations. In the case of high qubit oscillation  $B_{ij}^2; D_{ij}^2$  and weak measurement such as  $\eta = 1$ , we obtain  $D_{ij}^2 \ll B_{ij}^2$  in order of  $\eta^2$ . Then we have the eigenvalues of time-dependent matrix equations for  $|f_{aa}; c_c; a_c; c_a\rangle$  in order of  $B_{ij}^2 = (4, 0)$  as  $3B_{ij}^2, B_{ij}^2, 4i\omega_{ij}, 5=3^2$ , which shows that the period of qubit oscillation is delayed by the measurement through  $B_{ij}^2$  and  $D_{ij}^2$ . Thus we found that the qubit behavior strongly depends on the relative magnitude of  $\omega_{ij}$  to  $B_{ij}^2$  and this is also an important factor in the selection of the possible candidate of the logical basis. In Fig. 2(b) of  $\eta = 2 > D_{ij}^2 \gg 0.2$ ,  $F(t)$ s of  $|j_{Li}\rangle$  and  $|j_{Li}\rangle$  are larger than those of  $|j_{Li}\rangle$  (and  $|j_{Li}\rangle$ ). In Ref.<sup>19</sup>, we argued the coherent oscillation of the DM without the detector and showed that the DM for  $|j_{Li}\rangle$  and  $|j_{Li}\rangle$  are time-independent at  $\eta = 0$ . This indicates that  $|j_{Li}\rangle$  is the candidate in the  $B_{ij}^2; D_{ij}^2$  region, reflecting that  $|j_{Li}\rangle$  becomes an unpolarized triplet suffering less degradation from the repulsive Coulomb in-



<sup>21</sup> R. F. Werner, Phys. Rev. A 40, 4277 (1989).

<sup>22</sup> O. A. Stashev et al., cond-mat/0411216.